

## **INCHANGE SEMICONDUCTOR**

# isc N-Channel MOSFET Transistor

## IRFB7546,IIRFB7546

## FEATURES

- Static drain-source on-resistance:
  - Ros(on) ≤7.3mΩ
- Enhancement mode
- Fast Switching Speed
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

## DESCRITION

- Synchronous Rectifier applications
- Resonant mode power supplies
- Battery powered circuits

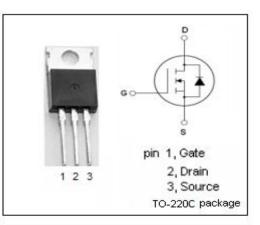
## • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

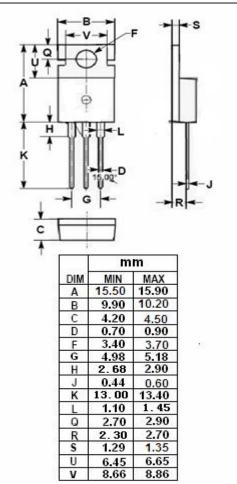
SYMBOL	PARAMETER	VALUE	UNIT			
V <sub>DSS</sub>	Drain-Source Voltage	60	V			
V <sub>GS</sub>	Gate-Source Voltage	±20	V			
ID	Drain Current-Continuous	75	А			
I <sub>DM</sub>	Drain Current-Single Pulsed	300	А			
PD	Total Dissipation @T <sub>c</sub> =25°C	99	W			
Tj	Max. Operating Junction Temperature 175		°C			
T <sub>stg</sub>	Storage Temperature	-55~175	°C			

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	1.52	℃ <b>/W</b>
Rth(ch-a)	Channel-to-ambient thermal resistance	62	°C/W

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## ELECTRICAL CHARACTERISTICS

T<sub>c</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; ID = 250µA	60			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; I <sub>D</sub> =100 μ A	2.1		3.7	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> =45A			7.3	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> =± 20V			±100	nA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =60V; V <sub>GS</sub> = 0V			1	μ Α
V <sub>SD</sub>	Diode forward voltage	Is =45A, V <sub>GS</sub> = 0 V			1.2	V

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